

# P54/74FCT399T/AT/CT FAST QUAD DUAL-PORT REGISTER

## FEATURES

- Function, Pinout and Drive Compatible with the FCT and F Logic
- FCT-C speed at 6.1ns max. (Com'I)  
FCT-A speed at 7.0ns max. (Com'I)
- Reduced  $V_{OH}$  (typically = 3.3V) versions of Equivalent FCT functions
- Edge-rate Control Circuitry for Significantly Improved Noise Characteristics
- ESD protection exceeds 2000V
- Power-off disable feature
- Matched Rise and Fall times
- Fully Compatible with TTL Input and Output Logic Levels
- 64 mA Sink Current (Com'I), 32 mA (Mil)  
15 mA Source Current (Com'I), 12 mA (Mil)
- Manufactured in 0.7 micron PACE Technology™

## DESCRIPTION

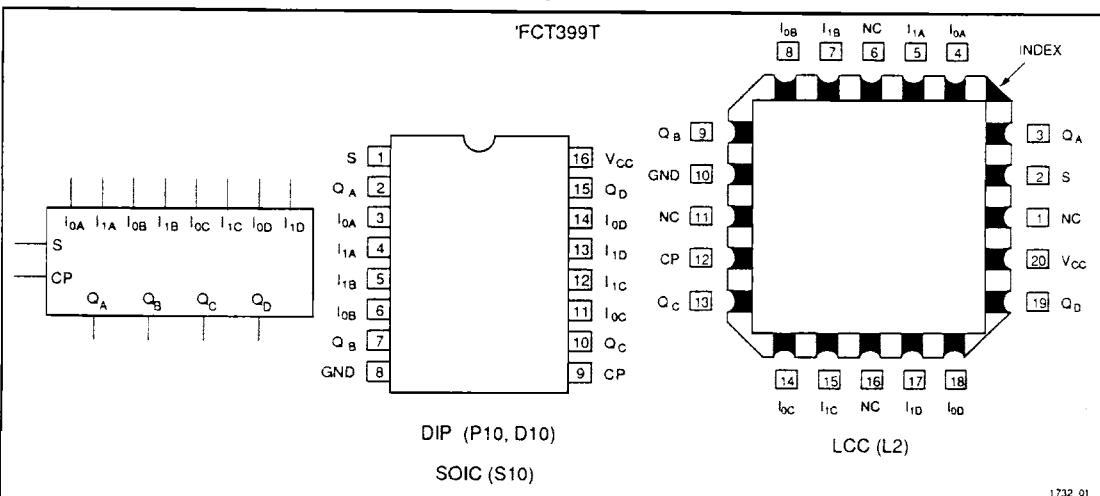
The 'FCT399T' is a high-speed quad dual-port registers that select four bits of data from either of two sources (Ports) under control of a common Select input (S). The selected data is transferred to a 4-bit output register synchronous with the LOW-to-HIGH transition of the Clock input (CP). The 4-bit D-type output register is fully edge-triggered. The Data inputs ( $I_{0X}, I_{1X}$ ) and Select input (S) must be stable only one set-up time prior to, and hold time after, the LOW-to-HIGH transition of the Clock input for predictable operation. The 'FCT399T' offers true outputs.

The 'FCT399T' is manufactured using PACE Technology™ which is Performance Advanced CMOS Engineered to use 0.7 micron effective channel lengths giving 400 picoseconds loaded\* internal gate delays. PACE Technology includes two-level metal and epitaxial substrates. In addition to very high performance and very high density, the technology features latch-up protection, single event upset protection, and is supported by a Class 1 environment volume production facility.

\*For a fan-in/fan-out of 4, at 85°C junction temperature and 5.0V.

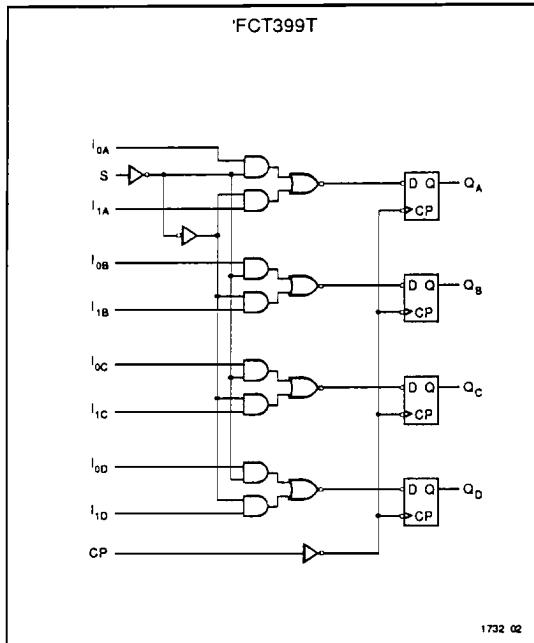
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## LOGIC SYMBOL AND PIN CONFIGURATIONS



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## FUNCTIONAL BLOCK DIAGRAM

ABSOLUTE MAXIMUM RATINGS<sup>1,2</sup>

Symbol	Parameter	Value	Unit
$T_{STG}$	Storage Temperature	-65 to +150	°C
$T_A$	Ambient Temperature Under Bias	-65 to +135	°C
$V_{CC}$	$V_{CC}$ Potential to Ground	-0.5 to +7.0	V
$P_T$	Power Dissipation	0.5	W
$I_{OUTPUT}$	Current Applied to Output	120	mA
$V_{IN}$	Input Voltage	-0.5 to +7.0	V
$V_{OUT}$	Voltage Applied to Output	-0.5 to +7.0	V

Notes:

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- Operation beyond the limits set forth in the above table may impair the useful life of the device. Unless otherwise noted, these limits are over the operating free-air temperature range.
- Unused inputs must always be connected to an appropriate logic voltage level, preferably either  $V_{CC}$  or ground.

## RECOMMENDED OPERATING CONDITIONS

Free Air Ambient Temperature	Min	Max
Military	-55°C	+125°C
Commercial	0°C	+70°C
Supply Voltage ( $V_{CC}$ )	Min	Max
Military	+4.5V	+5.5V
Commercial	+4.75V	+5.25V

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## DC ELECTRICAL CHARACTERISTICS (Over recommended operating conditions)

Symbol	Parameter		Min	Typ <sup>1</sup>	Max	Units	$V_{CC}$	Conditions
$V_{IH}$	Input HIGH Voltage		2.0			V		
$V_{IL}$	Input LOW Voltage				0.8	V		
$V_H$	Hysteresis			0.2		V		All inputs
$V_{IK}$	Input Clamp Diode Voltage			-0.7	-1.2	V	MIN	$I_{IN} = -18\text{mA}$
$V_{OH}$	Output HIGH Voltage	Military Commercial	2.4 2.4	3.3 3.3		V	MIN V	$I_{OH} = -12\text{mA}$ $I_{OH} = -15\text{mA}$
$V_{OL}$	Output LOW Voltage	Military Commercial Commercial		0.3 0.3 0.3	0.5 0.5 0.5	V	MIN V V	$I_{OL} = 32\text{mA}$ $I_{OL} = 48\text{mA}$ $I_{OL} = 64\text{mA}$
$I_I$	Input HIGH Current				20	$\mu\text{A}$	MAX	$V_{IN} = V_{CC}$
$I_{IH}$	Input HIGH Current				5	$\mu\text{A}$	MAX	$V_{IN} = 2.7\text{V}$
$I_{IL}$	Input LOW Current				-5	$\mu\text{A}$	MAX	$V_{IN} = 0.5\text{V}$
$I_{OS}$	Output Short Circuit Current <sup>2</sup>		-60	-120	-225	mA	MAX	$V_{OUT} = 0.0\text{V}$
$I_{OFF}$	Power-off Disable				100	$\mu\text{A}$	0V	$V_{OUT} = 4.5\text{V}$
$C_{IN}$	Input Capacitance <sup>3</sup>			5	10	pF	MAX	All inputs
$C_{OUT}$	Output Capacitance <sup>3</sup>			9	12	pF	MAX	All outputs
$I_{CC}$	Quiescent Power Supply Current			0.2	1.5	mA	MAX	$V_{IN} \leq 0.2\text{V}$ , $V_{IN} \geq V_{CC} - 0.2\text{V}$

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## Notes:

- Typical limits are at  $V_{CC} = 5.0\text{V}$ ,  $T_A = +25^\circ\text{C}$  ambient.
- Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged

shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests,  $I_{OS}$  tests should be performed last.

- This parameter is guaranteed but not tested.

**DC CHARACTERISTICS** (Over recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Typ. <sup>1</sup>	Max.	Units	Conditions
$\Delta I_{cc}$	Quiescent Power Supply Current (TTL inputs)	0.5	2.0	mA	$V_{cc} = MAX$ , $V_{in} = 3.4V^2$ , $f_i = 0$ , Outputs Open
$I_{ccd}$	Dynamic Power Supply Current <sup>3</sup>	0.15	0.25	mA/mHz	$V_{cc} = MAX$ , One Input Toggling, 50% Duty Cycle, Outputs Open, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
$I_c$	Total Power Supply Current <sup>5</sup>	1.7	4.0	mA	$V_{cc} = MAX$ , $f_o = 10MHz$ , 50% Duty Cycle, Outputs Open, One Input Toggling at $f_i = 5MHz$ , S = Steady State, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
		2.2	6.0	mA	$V_{cc} = MAX$ , $f_o = 10MHz$ , 50% Duty Cycle, Outputs Open, One Input Toggling at $f_i = 5MHz$ , S = Steady State, $V_{in} = 3.4V$ or $V_{in} = GND$
		4.0	7.8 <sup>4</sup>	mA	$V_{cc} = MAX$ , $f_o = 10MHz$ , 50% Duty Cycle, Outputs Open, 4 Inputs Toggling at $f_i = 5MHz$ , S = Steady State, $V_{in} \leq 0.2V$ or $V_{in} \geq V_{cc} - 0.2V$
		5.2	12.8 <sup>4</sup>	mA	$V_{cc} = MAX$ , $f_o = 10MHz$ , 50% Duty Cycle, Outputs Open, 4 Inputs Toggling at $f_i = 5MHz$ , S = Steady State, $V_{in} = 3.4V$ or $V_{in} = GND$

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**Notes:**

1. Typical values are at  $V_{cc} = 5.0V$ , +25°C ambient and maximum loading.
2. Per TTL driven input ( $V_{in} = 3.4V$ ); all other inputs at  $V_{cc}$  or GND.
3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
4. Values for these conditions are examples of the  $I_c$  formula. These limits are guaranteed but not tested.
5.  $I_c = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$   
 $I_c = I_{cc} + \Delta I_{cc} D_{in} N_t + I_{ccd} (f_o/2 + I_t N_t)$   
 $I_{cc}$  = Quiescent Current with CMOS input levels

$\Delta I_{cc}$  = Power Supply Current for a TTL High Input  
 $(V_{in} = 3.4V)$

$D_{in}$  = Duty Cycle for TTL Inputs High

$N_t$  = Number of TTL Inputs at  $D_{in}$

$I_{ccd}$  = Dynamic Current Caused by an Input Transition Pair (LHL or LHL)

$f_o$  = Clock Frequency for Register Devices (Zero for Non-Register Devices)

$f_i$  = Input Frequency

$N_t$  = Number of Inputs at  $f_i$

All currents are in millamps and all frequencies are in megahertz.

**FUNCTION TABLE — 'FCT399T**

Inputs			Outputs
S	$I_0$	$I_1$	Q
I	I	X	L
I	h	X	H
h	X	I	L
h	X	h	H

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H = HIGH Voltage Level

L = LOW Voltage Level

h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH Clock Transition

I = LOW Voltage Level one setup time prior to the LOW-to-HIGH Clock Transition

X = Don't Care

**PIN DESCRIPTION**

Pin Names	Description
S	Common Select Input
CP	Clock Pulse Input (Active Rising Edge)
$I_{OA} - I_{OD}$	Data Inputs from Source 0
$I_{IA} - I_{ID}$	Data Inputs from Source 1
$Q_A - Q_D$	Register True Outputs

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**AC CHARACTERISTICS**

Symbol	Parameter	'FCT399T				'FCT399AT				'FCT399CT				Units	Fig. No.		
		MIL		COM'L		MIL		COM'L		MIL		COM'L					
		Min. <sup>1</sup>	Max.														
$t_{PLH}$	Propagation Delay CP to Q	3.0	11.5	3.0	10.0	2.5	7.5	2.5	7.0	2.5	6.6	2.5	6.1	ns	1, 5		

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**Note:**

1. AC Characteristics guaranteed with  $C_L = 50\text{pF}$  as shown in Figure 1.

**AC OPERATING REQUIREMENTS**

Symbol	Parameter	'FCT399T				'FCT399AT				'FCT399CT				Units	Fig. No.		
		MIL		COM'L		MIL		COM'L		MIL		COM'L					
		Min. <sup>1</sup>	Max.														
$t_s(H)$	Setup Time, $I_n(L)$ to CP	4.5	—	4.0	—	4.0	—	3.5	—	4.0	—	3.5	—	ns	4		
$t_h(H)$	Hold Time, $I_n(L)$ to CP	1.5	—	1.0	—	1.0	—	1.0	—	1.0	—	1.0	—	ns	4		
$t_s(H)$	Set-up Time, $SP(L)$ to CP	9.5	—	9.0	—	9.0	—	8.5	—	9.0	—	8.5	—	ns	4		
$t_h(H)$	Hold Time, $SP(L)$ to CP	0	—	0	—	0	—	0	—	0	—	0	—	ns	4		
$t_w(H)$	Clock Pulse Width <sup>2</sup> , $I_n(L)$	7.0	—	5.0	—	6.0	—	5.0	—	6.0	—	5.0	—	ns	5		

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**Notes:**

1. Minimum limits are guaranteed but not tested on Propagation Delays.  
2. This parameter is guaranteed but not tested.

## ORDERING INFORMATION

PxxFCT Temp. Class	xxxx Device type	X Package	X Processing		
				Blank	Commercial
				M	Military Temperature
				B	MIL-STD-883, Class B
				P	Plastic DIP
				D	CERDIP
				SO	Small Outline IC
				L	Leadless Chip Carrier
				399T	Quad Dual-Port-Register
				399AT	Fast Quad Dual-Port-Register
				399CT	Ultra Fast Quad Dual-Port-Register
				74	Commercial
				54	Military

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